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RF2044

GENERAL PURPOSE AMPLIFIER

RoHS Compliant & Pb-Free Product Package Style: Micro-X Ceramic

Features

- DC to >6000 MHz Operation
- Internally matched Input and Output
- 20dB Small Signal Gain
- 4.0dB Noise Figure
- 50mW Linear Output Power
- Single Positive Power Supply

Applications

- Broadband, Low-Noise Gain Blocks
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers
- Final PA for Low-Power Applications
- High Reliability Applications
- Broadband Test Equipment





Functional Block Diagram

Product Description

The RF2044 is a general purpose, low-cost RF amplifier IC. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as an easily-cascadable 50 Ω gain block. Applications include IF and RF amplification in wireless voice and data communication products operating in frequency bands up to 6000MHz. The device is self-contained with 50 Ω input and output impedances and requires only two external DC biasing elements to operate as specified. With a goal of enhanced reliability, the extremely small Micro-X ceramic package offers significantly lower thermal resistance than similar size plastic packages.

Ordering Information

RF2044General Purpose AmplifierRF204XPCBA-41XFully Assembled Evaluation Board

Optimum Technology Matching® Applied

🗹 GaAs HBT	□ SiGe BiCMOS	🗌 GaAs pHEMT	🗌 GaN HEMT
GaAs MESFET	🗌 Si BiCMOS	Si CMOS	
🗌 InGaP HBT	SiGe HBT	🗌 Si BJT	

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Absolute Maximum Ratings

Parameter	Rating	Unit
Input RF Power	+13	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-60 to +150	°C



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RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

Devenuetev	Specification		1124	O an diti a n		
Parameter	Min.	Тур.	Max.	Unit	Condition	
Overall					T=25 °C, I _{CC} =65mA	
Frequency Range		DC to >6000		MHz		
3dB Bandwidth		>3		GHz		
Gain		20.2		dB	Freq=100MHz	
	19.3	20.1	21.3	dB	Freq=850MHz	
	16.5	19.4		dB	Freq=2000MHz	
		18.2		dB	Freq=3000MHz	
		17.0			Freq=4000MHz	
		14.1			Freq=6000MHz	
Gain Flatness		±0.4		dB	100 MHz to 2000 MHz	
Noise Figure		3.6		dB	Freq=1000MHz	
Input VSWR		<1.6:1			In a 50 Ω system, DC to 5000 MHz	
		<1.5:1			In a 50 Ω system, 5000 MHz to 6000 MHz	
Output VSWR		<1.4:1			In a 50 Ω system, DC to 3000 MHz	
		<1.5:1			In a 50 Ω system, 3000 MHz to 6000 MHz	
Output IP ₃	+30.0	+33.5		dBm	Freq=1000MHz	
Output P _{1dB}		+18.5		dBm	Freq=1000MHz	
Reverse Isolation		22.6		dB	Freq=1000MHz	
Thermal					I _{CC} =65mA, P _{DISS} =299mW (See Note 1.)	
Theta _{JC}		260		°C/W	V _{PIN} =4.61V	
Maximum Measured Junction Temperature at DC Bias Condi- tions		163		°C	T _{AMB} =+85°C	
Mean Time To Failure		2290		years	T _{AMB} =+85 °C	
Power Supply					With 22Ω bias resistor, T=+25°C	
Device Operating Voltage	4.3	4.8	5.3	V	At pin 3 with I _{CC} =65mA	
	5.7	6.3	6.7	V	At evaluation board connector, I _{CC} =65mA	
Operating Current			65	mA	See Note 2.	

NOTES:

Note 1: The RF2044 must be operated at or below 65 mA in order to achieve the thermal performance stated above. Operating at 65 mA will ensure the best possible combination of reliability and electrical performance.

Note 2: Because of process variations from part to part, the current resulting from a fixed bias voltage will vary. As a result, caution should be used in designing fixed voltage bias circuits to ensure the worst case bias current does not exceed 65 mA over all intended operating conditions.



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RF2044

Pin	Function	Description	Interface Schematic
1	RF IN	RF input pin. This pin is NOT internally DC-blocked. A DC-blocking capacitor, suitable for the frequency of operation, should be used in most applica- tions. DC-coupling of the input is not allowed, because this will override the internal feedback loop and cause temperature instability.	
2	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
3	RF OUT	RF output and bias pin. Biasing is accomplished with an external series resistor and choke inductor to V _{CC} . The resistor is selected to set the DC current into this pin to a desired level. The resistor value is determined by the following equation: $R = \frac{(V_{SUPPLY} - V_{DEVICE})}{I_{CC}}$ Care should also be taken in the resistor selection to ensure that the current into the part never exceeds 65 mA over the planned operating temperature . This means that a resistor between the supply and this pin is always required, even if a supply near 4.8V is available, to provide DC feedback to prevent thermal runaway. Because DC is present on this pin, a DC-blocking capacitor, suitable for the frequency of operation, should be used in most applications. The supply side of the bias network should also be well bypassed.	
4	GND	Same as pin 2.	

Package Drawing





Application Schematic







Evaluation Board Schematic





Junction Temperature (°C)

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200.0



7.0

4.60











Output VSWR versus Frequency Across Temperature Icc=65mA



1.50

3000.00

Frequency (MHz)

4000.00

2000.00

Rev A18 DS070403

0.00

1000.00

VSWR

1.25

1.00

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+ -40°C

- 25°C

▲ 85°C

6000.00

5000.00





PCB Design Requirements

PCB Surface Finish

The PCB surface finish used for RFMD's qualification process is Electroless Nickel, immersion Gold. Typical thickness is 3µinch to 8µinch Gold over 180µinch Nickel.

PCB Land Pattern Recommendation

PCB land patterns are based on IPC-SM-782 standards when possible. The pad pattern shown has been developed and tested for optimized assembly at RFMD; however, it may require some modifications to address company specific assembly processes. The PCB land pattern has been developed to accommodate lead and package tolerances.

PCB Metal Land Mask Pattern



Figure 1. PCB Metal Land Pattern - RF204X (Top View)

PCB Solder Mask Pattern

Liquid Photo-Imageable (LPI) solder mask is recommended. The solder mask footprint will match what is shown for the PCB metal land pattern with a 2mil to 3mil expansion to accommodate solder mask registration clearance around all pads. The center-grounding pad shall also have a solder mask clearance. Expansion of the pads to create solder mask clearance can be provided in the master data or requested from the PCB fabrication supplier.









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